DATA SHEET



MOS FIELD EFFECT TRANSISTOR 2SK3298

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3298 is N-channel MOS FET device that features a low gate charge and excellent switching characteristics, designed for high voltage applications such as switching power supply, AC adapter.

ORDERING INFORMATION

PART NUMBER	PACKAGE			
2SK3298	Isolated TO-220			

FEATURES

- •Low gate charge
- $Q_G = 34 \text{ nC TYP.}$ ($V_{DD} = 450 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 7.5 \text{ A}$)
- •Gate voltage rating ±30 V
- •Low on-state resistance

RDS(on) = 0.75Ω MAX. (VGS = 10 V, ID = 4.0 A)

- Avalanche capability ratings
- •Isolated TO-220 package

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vss = 0 V)	Voss	600	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±30	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±7.5	Α
Drain Current (Pulse) Note1	ID(pulse)	±30	Α
Total Power Dissipation (T _A = 25°C)	P _{T1}	2.0	W
Total Power Dissipation (Tc = 25°C)	P _{T2}	40	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	7.5	Α
Single Avalanche Energy Note2	Eas	37.5	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1 %

2. Starting T_{ch} = 25 °C, V_{DD} = 150 V, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

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The mark ★ shows major revised points.

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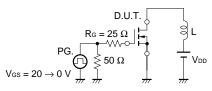
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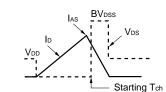
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ELECTRICAL CHARACTERISTICS(TA = 25°C)

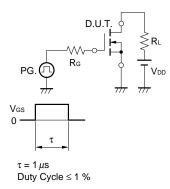
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Leakage Current	Ioss	V _{DS} = 600 V, V _{GS} = 0 V			100	μΑ
Gate Leakage Current	Igss	Vgs = ±30 V, Vps = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	2.5		3.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 4.0 A	3.2			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, ID = 4.0 A		0.67	0.75	Ω
Input Capacitance	Ciss	V _{DS} = 10 V		1580		pF
Output Capacitance	Coss	Vgs = 0 V		280		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		25		pF
Turn-on Delay Time	t _{d(on)}	ID = 4.0 A		27		ns
Rise Time	tr	V _{GS(on)} = 10 V		14		ns
Turn-off Delay Time	t _{d(off)}	V _{DD} = 150 V		66		ns
Fall Time	tr	$R_G = 10 \Omega$		24		ns
Total Gate Charge	QG	ID = 7.5 A		34		nC
Gate to Source Charge	Qgs	V _{DD} = 450 V		8.2		nC
Gate to Drain Charge	Q _{GD}	Vgs = 10 V		12.3		nC
Diode Forward Voltage	V _{F(S-D)}	IF = 7.5 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 7.5 A, VGS = 0 V		1.6		μs
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		9.0		μC

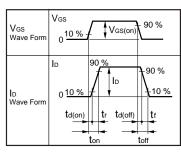
★ TEST CIRCUIT 1 AVALANCHE CAPABILITY





TEST CIRCUIT 2 SWITCHING TIME

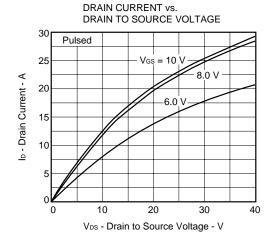


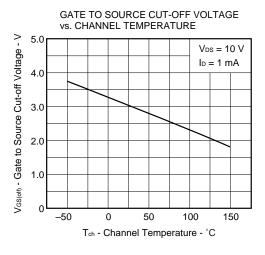


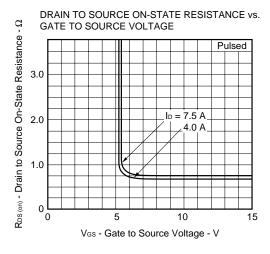
TEST CIRCUIT 3 GATE CHARGE

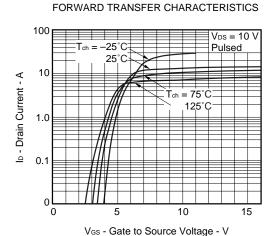
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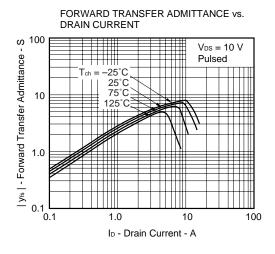
★ TYPICAL CHARACTERISTICS (TA = 25 °C)

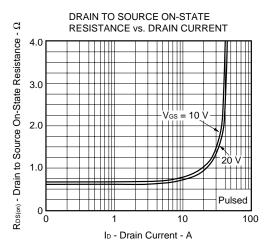


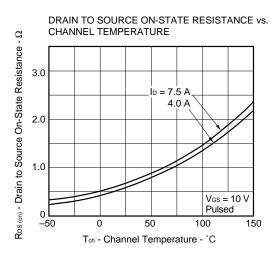


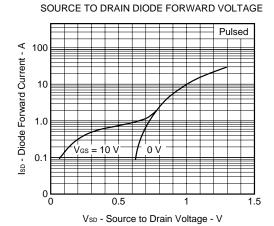


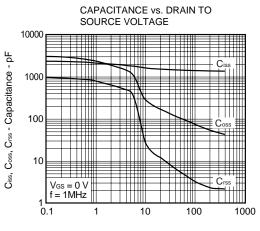


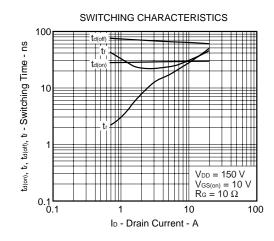




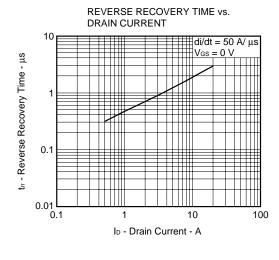


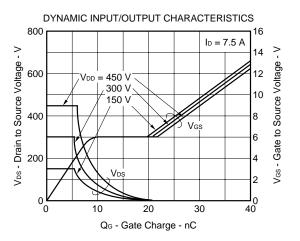


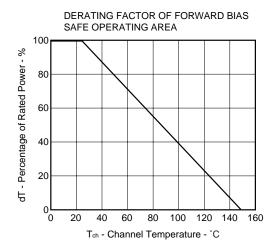


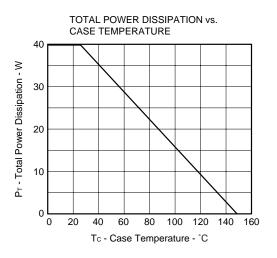


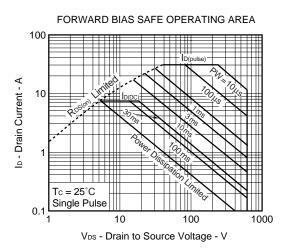


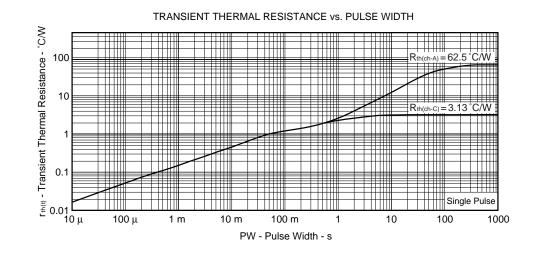




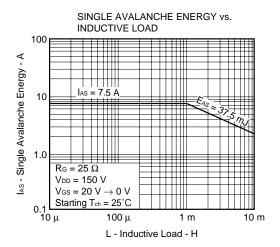


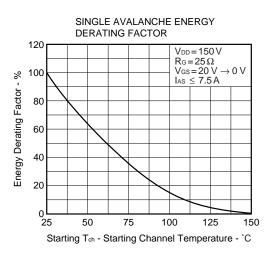






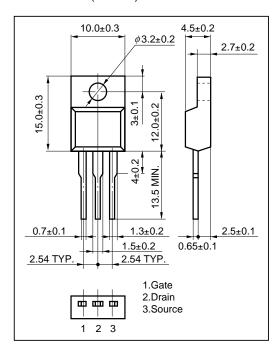
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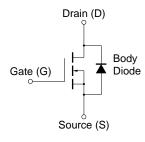


PACKAGE DRAWING (Unit: mm)

Isolated TO-220 (MP-45F)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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